

View Online at <https://aerobasegroup.com/nsn/5961-01-245-3669>

**Inclosure Material:**

Ceramic

**Overall Length:**

0.785 inches

**Overall Height:**

0.200 inches

**Overall Width:**

0.325 inches

**Joint Electronic Device Engineering Council/jedec/case Outline Designation:**

To-116

**Component Name And Quantity:**

4 transistor

**Mounting Method:**

Press fit

**Features Provided:**

Electrostatic sensitive and hermetically sealed case

**Semiconductor Material:**

Silicon all transistor

**Voltage Rating In Volts Per Characteristic:**

-40.0 collector to emitter voltage, dc all transistor and -40.0 collector to base voltage, dc all transistor and -5.0 emitter to base voltage, dc all transistor

**Current Rating Per Characteristic:**

-1.00 amperes source cutoff current all transistor

**Power Rating Per Characteristic:**

6.3 watts small-signal input power, common-collector absolute all transistor

**Transfer Ratio:**

20.0 static forward current transfer ratio, common-emitter all transistor

**Maximum Operating Temperature Per Measurement Point:**

200.0 degrees celsius ambient air

**Special Features:**

All transistor junction pattern arrangement: pnp

**Terminal Type And Quantity:**

14 uninsulated wire lead

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

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